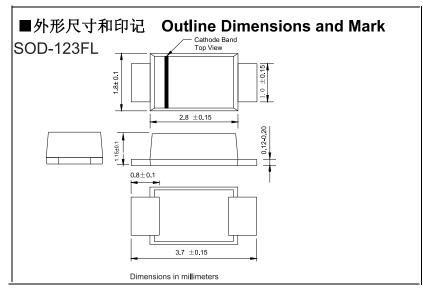
S12 THRU S110



■特征 Features

• I_o 1.0A

• V_{RRM} 20V-100V

• 耐正向浪涌电流能力高

High surge current capability

● 封装: 模压塑料

Cases: Molded plastic

■用途 Applications

●整流用 Rectifier

■极限值(绝对最大额定值)

Limiting Values (Absolute Maximum Rating)

参数名称	符号	单位	泣 测试条件		S	S	S	S	S	S
Item	Symbol	ol Unit Test Conditions		12	13	14	15	16	19	110
反向重复峰值电压 Repetitive Peak Reverse Voltage	V_{RRM}	V		20	30	40	50	60	90	100
正向平均电流 Average Forward Current	I _{F(AV)}	А	正弦半波 60Hz, 电阻负载,Ta=50℃ 60Hz Half-sine wave, Resistance load, Ta=50℃	1.0						
正向(不重复)浪涌电流 Surge(Non-repetitive)Forward Current	I _{FSM}	А	正弦半波 60Hz, 一个周期, Ta=25℃ 60Hz Half-sine wave ,1 cycle , Ta =25℃	30						
结温 Junction Temperature	TJ	$^{\circ}$ C		-55~+125						
储存温度 Storage Temperature	T _{STG}	$^{\circ}$		-55 ~ +150						

■电特性 (Ta=25°C 除非另有规定)

Electrical Characteristics (Ta=25°C Unless otherwise specified)

参数名称 Item	符号 Symbol	单位 Unit	测i Test Co	S 12	S 13	S 14	S 15	S 16	S 19	S 110	
正向峰值电压 Peak Forward Voltage	V _F	V	l _F =	0.55			0.70		0.85		
反向漏电流 Peak Reverse Current	I _{R1}	A	V _{RM} =V _{RRM}	T _a =25℃	0.5						
	I _{R2}	mA		T _a =100℃		10		5.0		2.0	
热阻(典型) Thermal Resistance(Typical)	$R_{\theta J-A}$	°C/W	结和环境之间 Between junction and ambient		88 ¹⁾						
	R _{θJ-L}	C/VV	结和约 Between junct	28 ¹⁾							

备注: Notes:

Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pad areas

 $^{^{1)}}$ 热阻从结到环境及从结到引线,在电路板的 $0.2" \times 0.2"$ (5.0毫米 $\times 5.0$ 毫米)铜垫片区

